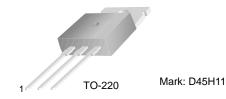
October 2008



SEMICONDUCTOR®

D45H11 PNP Power Amplifier

- This device is designed for power amplifier, regulatro and switching circuits where speed is important.
- Sourced from process 5Q.



1. Base 2. Collector 3. Emitter

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	-80	V
Ι _C	Collector Current - Continuous	-10	A
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 to +150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Charac	teristics			1	
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = -100 {\rm mA}, \ I_{\rm B} = 0$	-80		V
I _{CBO}	Collector-Cutoff Current	$V_{CB} = -80V, I_{E} = 0$		-10	μA
I _{EBO}	Emitter-Cutoff Current	$V_{EB} = -5V, I_C = 0$		-100	μA
On Charac	teristics *	·			
h _{FE}	DC Current Gain	$V_{CE} = -1V, I_C = -2A$ $V_{CE} = -1V, I_C = -4A$	60 40		
V _{CE (sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C} = -8A, I_{\rm B} = -0.4A$		-1.0	V
V _{BE (sat)}	Base-Emitter Saturation Voltage	$I_{\rm C} = -8A, I_{\rm B} = -0.8A$		-1.5	V
V _{BE (on)}	Base-Emitter On Voltage	V _{CE} = -2V, I _C = -10mA	-0.54	-0.65	V
	al Characteristics	· · ·	•	•	•
f _T	Current Gain Bandwidth Product	I _C = -500mA, V _{CE} = -10V	40		MHZ

Thermal Characteristics $T_a=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation Derate above 25°C	60 480	mW mW/°C
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case	2.1	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	62.5	°C/W

* Note) Device mounted on FR-\$ PCB 36mm*18mm*1.5mm: Mounting pad for the collector lead min. 6cm2.



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